

NPN SILICON RF TRANSISTOR NE85634 / 2SC3357 JEITA Part No.

NPN EPITAXIAL SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW-NOISE AMPLIFICATION 3-PIN POWER MINIMOLD

FEATURES

- · Low noise and high gain
- ★ NF = 1.1 dB TYP., $G_a = 7.5$ dB TYP. @ VcE = 10 V, Ic = 7 mA, f = 1 GHz NF = 1.8 dB TYP., $G_a = 9.0$ dB TYP. @ VcE = 10 V, Ic = 40 mA, f = 1 GHz
- ★ High power gain : MAG = 10 dB TYP. @ Ic = 40 mA, f = 1 GHz
 - Large Ptot: Ptot = 1.2 W (Mounted on 16 cm² × 0.7 mm (t) ceramic substrate)
 - · Small package: 3-pin power minimold package

★ ORDERING INFORMATION

Part Number	Quantity	Supplying Form
NE85634-A 2SC3357-A	25 pcs (Non reel)	12 mm wide embossed taping Collector face the perfection side of the tape.
NE85634-T1-A 2SC3357-T1-A	1 kpcs/reel	Collector face the perforation side of the tape

Remark To order evaluation samples, contact your nearby sales office.

The unit sample quantity is 25 pcs.

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	20	V
Collector to Emitter Voltage	Vceo	12	V
Emitter to Base Voltage	VEBO	3.0	V
Collector Current	lc	100	mA
Total Power Dissipation	Ptot Note	1.2	W
Junction Temperature	Tj	150	°C
Storage Temperature	T _{stg}	-65 to +150	°C

Note Mounted on 16 cm² × 0.7 mm (t) ceramic substrate

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version

THERMAL RESISTANCE

Parameter	Symbol	Value	Unit
Junction to Ambient Resistance	Rth (j-a) Note	62.5	°C/W

Note Mounted on 16 cm² × 0.7 mm (t) ceramic substrate

ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	ICBO		-	-	1.0	μΑ
Emitter Cut-off Current	ГЕВО	VEB = 1.0 V, Ic = 0 mA	-	_	1.0	μΑ
DC Current Gain	hfE Note 1	Vce = 10 V, Ic = 20 mA	50	120	250	_
RF Characteristics						
Gain Bandwidth Product	f⊤	Vce = 10 V, Ic = 20 mA	_	6.5	_	GHz
Insertion Power Gain	S _{21e} ²	Vce = 10 V, Ic = 20 mA, f = 1 GHz	-	9.0	_	dB
Noise Figure (1)	NF	Vce = 10 V, Ic = 7 mA, f = 1 GHz	_	1.1	_	dB
Noise Figure (2)	NF	Vce = 10 V, Ic = 40 mA, f = 1 GHz	-	1.8	3.0	dB
Reverse Transfer Capacitance	Cre Note 2	VcB = 10 V, IE = 0 mA, f = 1 MHz	1	0.65	1.0	pF

Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

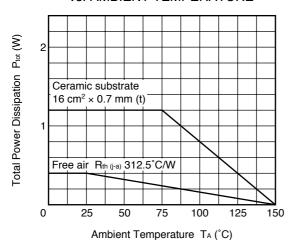
2. The emitter terminal and the case shall be connected to the guard terminal of the three-terminal capacitance bridge.

hfe CLASSIFICATION

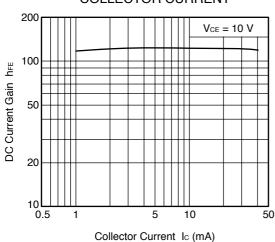
Rank	RH	RF	RE
Marking	RH	RF	RE
h _{FE} Value	50 to 100	80 to 160	125 to 250

TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

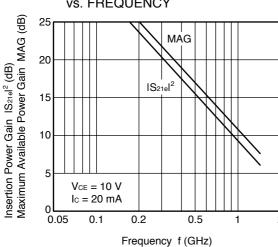
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



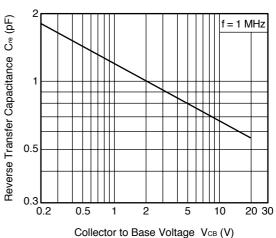
DC CURRENT GAIN vs. **COLLECTOR CURRENT**



INSERTION POWER GAIN, MAG vs. FREQUENCY

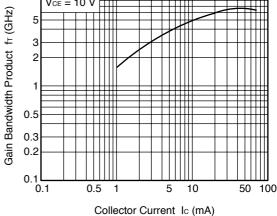


REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE

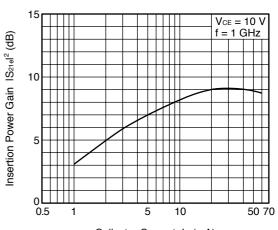


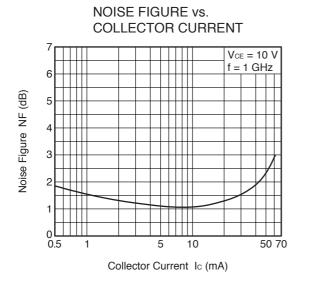
GAIN BANDWIDTH PRODUCT

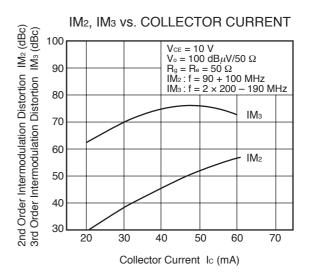




INSERTION POWER GAIN vs. COLLECTOR CURRENT





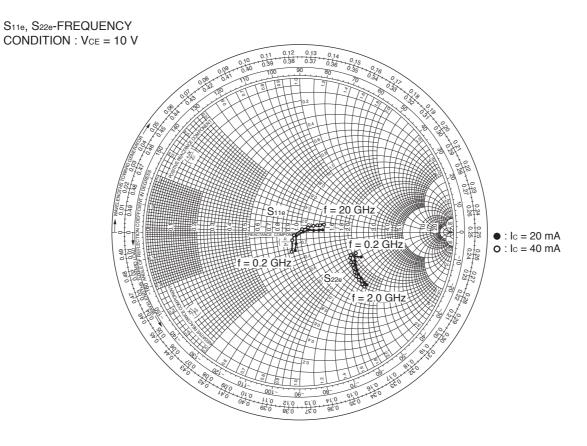


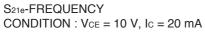
Remark The graphs indicate nominal characteristics.

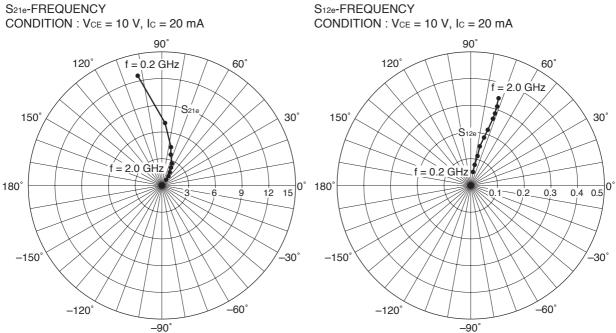
S-PARAMETERS

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- · Click here to download S-parameters.
- [RF and Microwave] ® [Device Parameters]
- · URL http://www.necel.com/microwave/en/

SMITH CHART

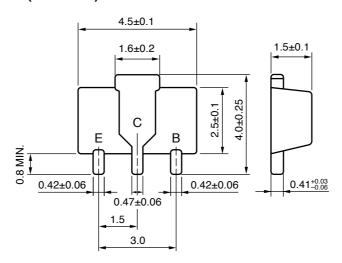






★ PACKAGE DIMENSIONS

3-PIN POWER MINIMOLD (UNIT: mm)



PIN CONNECTIONS

E : Emitter

C: Collector (Fin)

B: Base

(IEC: SOT-89)

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